

K30A O 1D ("2nd Group Buy" No01)

N-Ch JFET

Red-G, Symmetrical Src/Drn

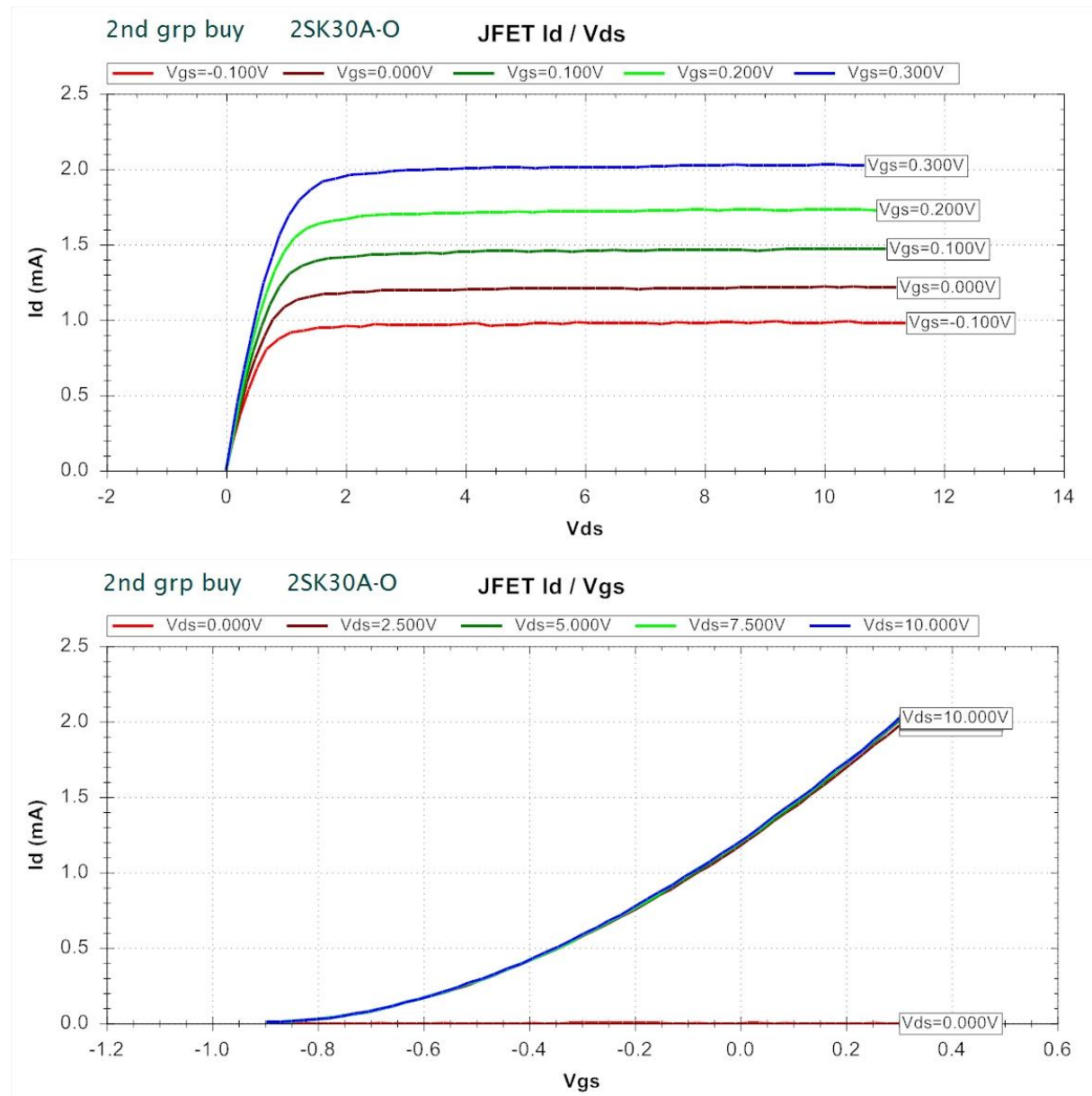
$V_{gs(off)} = -0.90V$ at $I_d = 4.8\mu A$

$V_{gs(on)} = 0.28V$ at $I_d = 1.92mA$

$g_{fs} = 2.7mA/V$ at $I_d = 1.2mA$ to $1.9mA$

$I_{dss} = 1.19mA$ at $V_{ds} = 3.00V$

$R_{ds(on)} = 418.7\Omega$ at $I_d = 1.9mA$ and $V_{gs} = 0.0V$



K30A Y 3E ("2nd Group Buy" No01)

N-Ch JFET

Red-G, Symmetrical Src/Drn

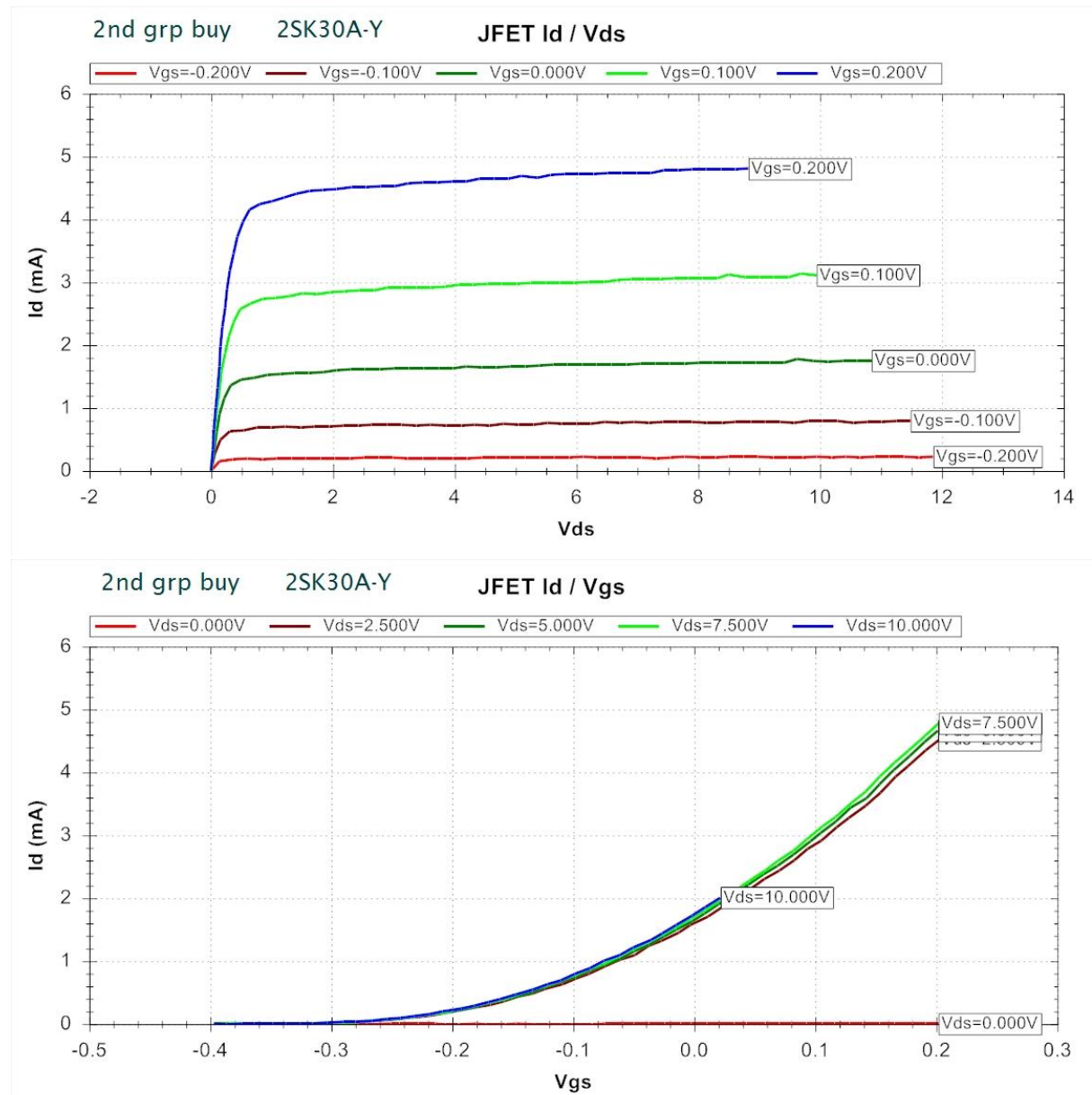
$V_{gs(off)} = -0.36V$ at $I_d = 4.5\mu A$

$V_{gs(on)} = 0.22V$ at $I_d = 5.00mA$

$g_{fs} = 17.8mA/V$ at $I_d = 3.0mA$ to $5.0mA$

$I_{dss} = 1.70mA$ at $V_{ds} = 3.00V$

$R_{ds(on)} = 42.8\Omega$ at $I_d = 5.0mA$ and $V_{gs} = 0.0V$



C1583 86F ("2nd Group Buy" No01)

NPN Silicon BJT

Red-C Green-B Blue-E

$h_{FE} = 379$ at $I_c = 5.01mA$

$V_{be}=0.764V$ at $I_b=5.00mA$

$V_{ceSat}=0.033V$ at $I_c=5.0mA$ and $I_b=1.00mA$

$I_{cLeak}=0.000mA$

NPN Silicon BJT

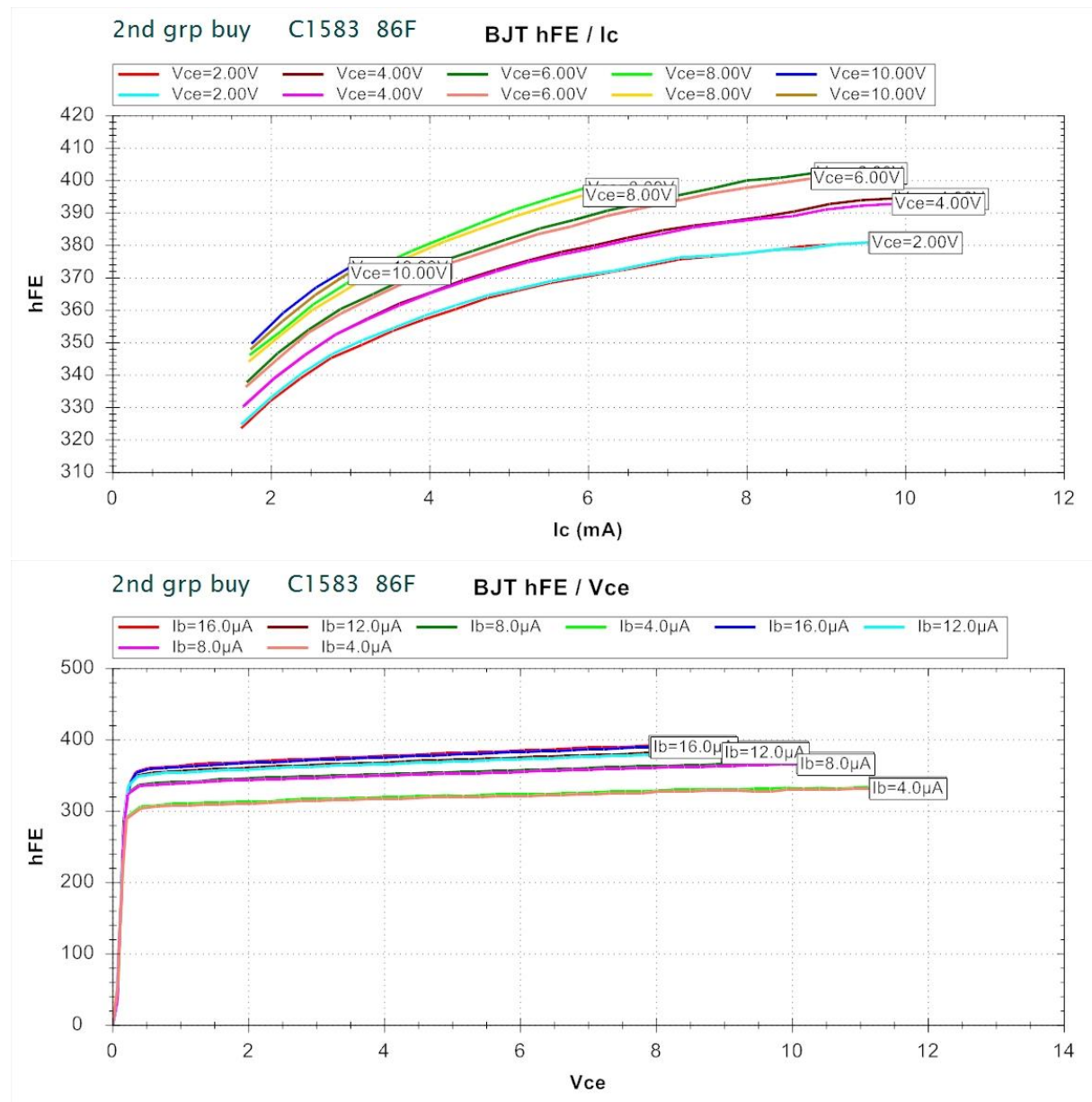
Red-C Green-B Blue-E

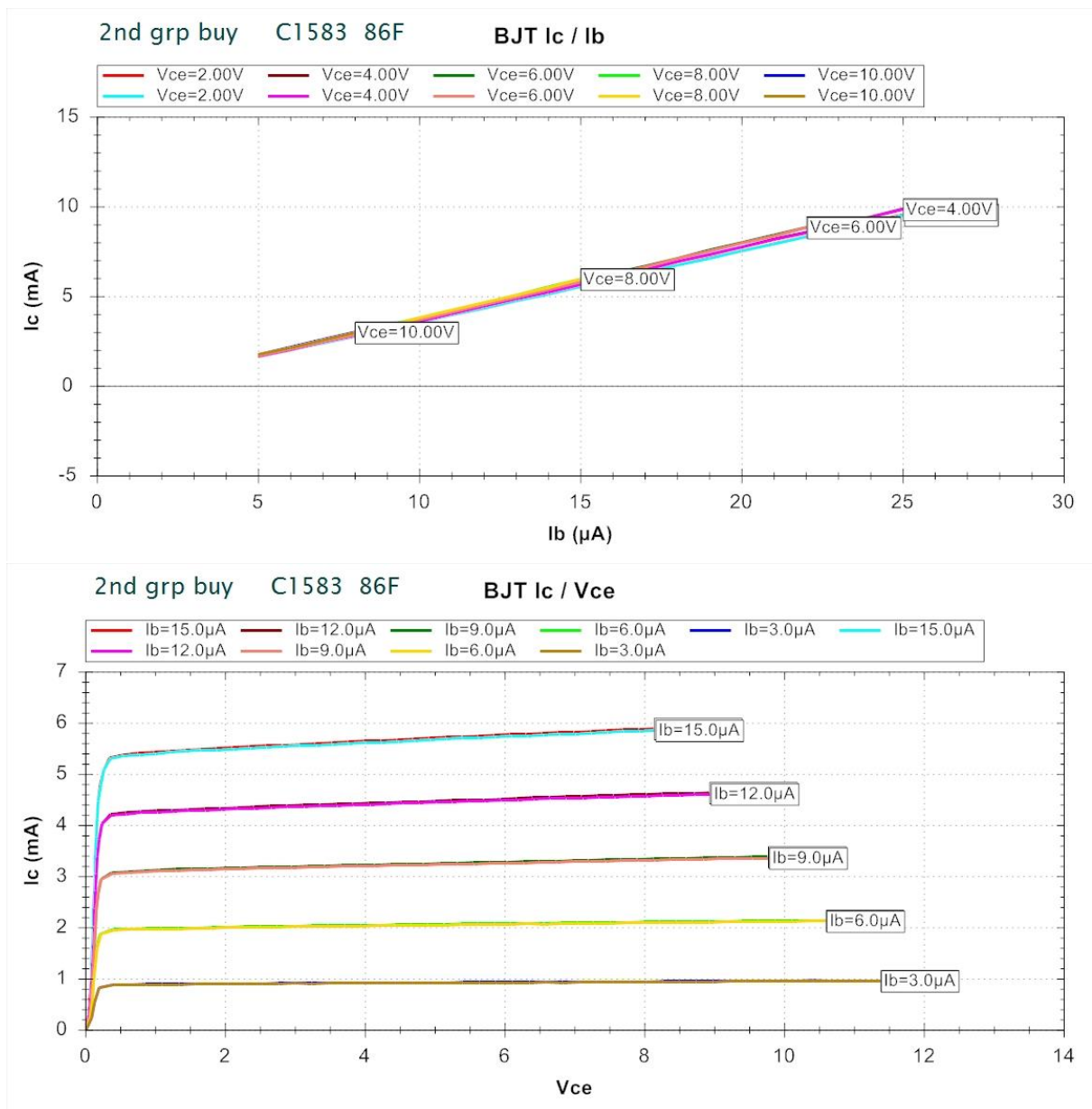
$hFE=370$ at $I_c=4.99mA$

$V_{be}=0.768V$ at $I_b=5.00mA$

$V_{ceSat}=0.033V$ at $I_c=5.0mA$ and $I_b=1.00mA$

$I_{cLeak}=0.000mA$





C1583 86F ("2nd Group Buy" No02)

NPN Silicon BJT

Red-E Green-C Blue-B

$h_{FE}=421$ at $I_c=5.02\text{mA}$

$V_{be}=0.762\text{V}$ at $I_b=5.00\text{mA}$

$V_{ceSat}=0.036\text{V}$ at $I_c=5.0\text{mA}$ and $I_b=1.00\text{mA}$

$I_{cLeak}=0.000\text{mA}$

NPN Silicon BJT

Red-E Green-C Blue-B

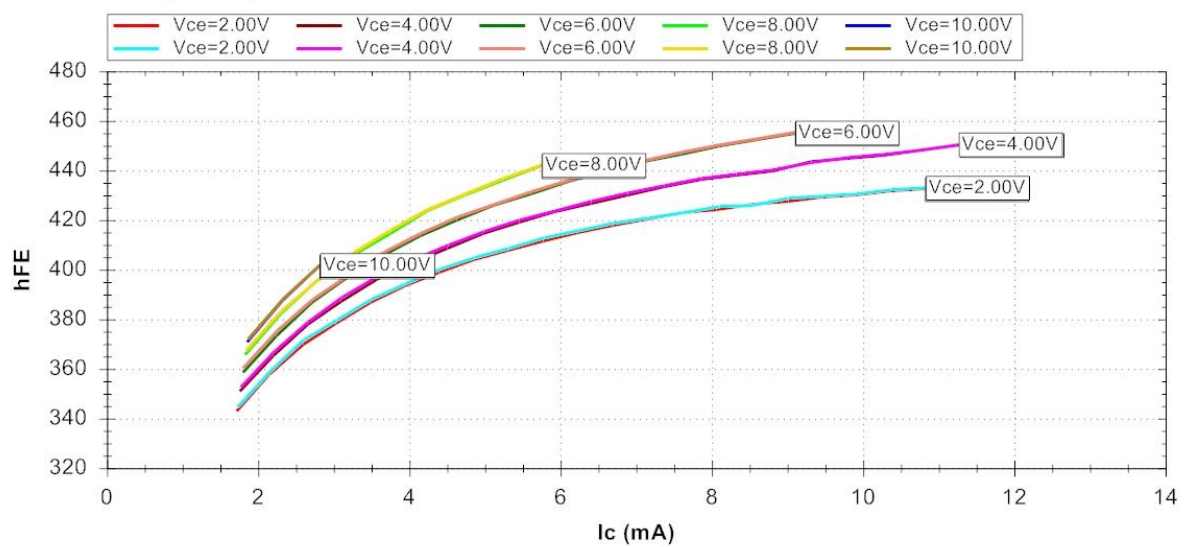
$h_{FE}=425$ at $I_c=5.00\text{mA}$

$V_{be}=0.758\text{V}$ at $I_b=5.00\text{mA}$

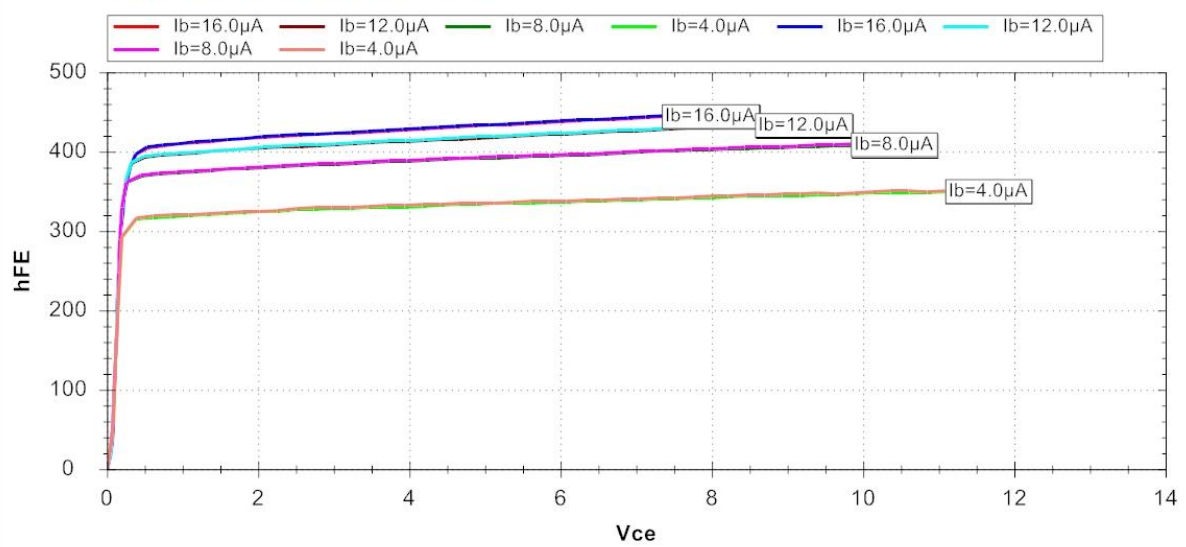
$V_{ceSat}=0.037\text{V}$ at $I_c=5.0\text{mA}$ and $I_b=1.00\text{mA}$

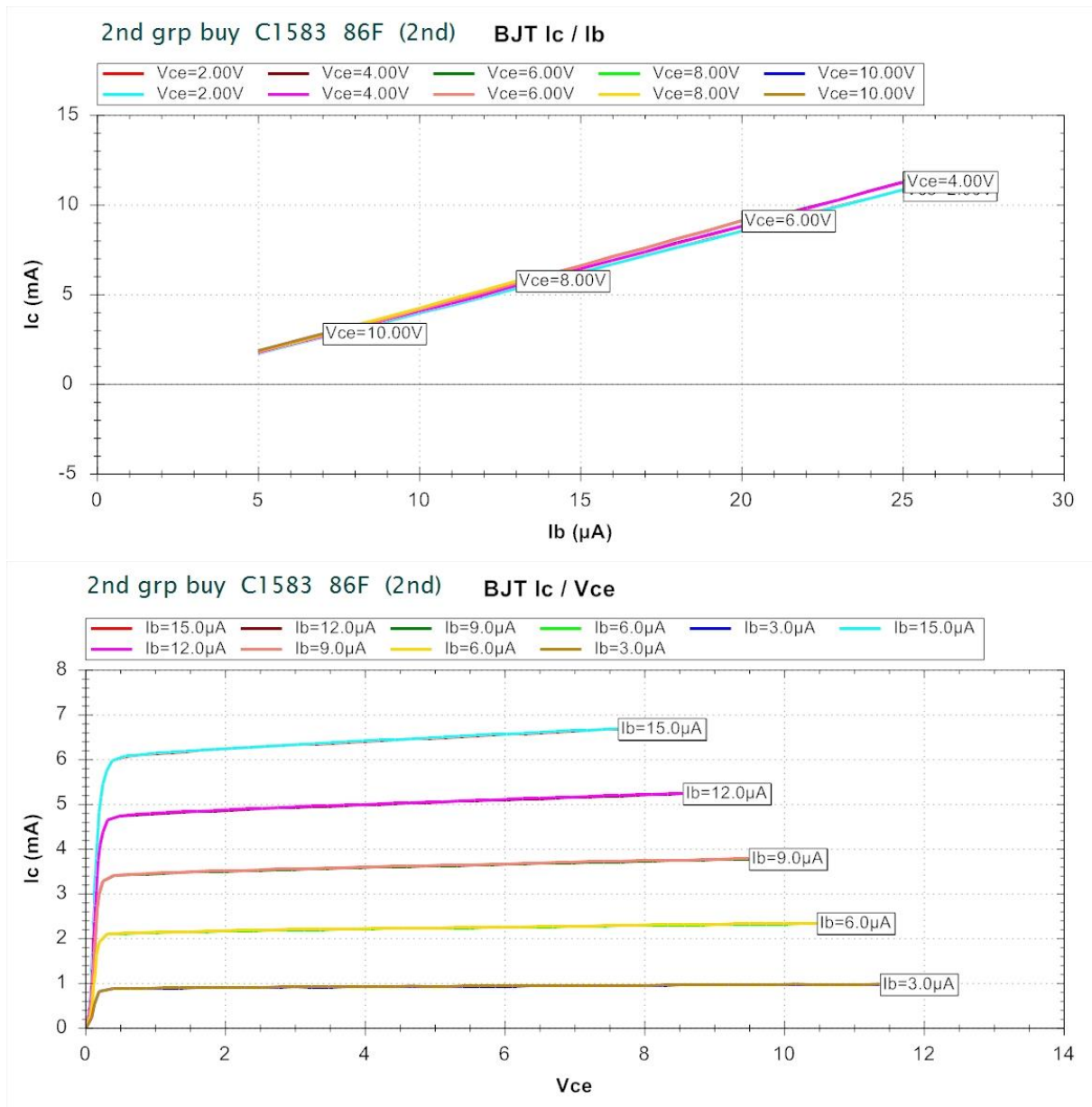
IcLeak=0.000mA

2nd grp buy C1583 86F (2nd) BJT hFE / Ic



2nd grp buy C1583 86F (2nd) BJT hFE / Vce





C1583 86F ("2nd Group Buy" No03)

NPN Silicon BJT

Red-B Green-E Blue-C

$h_{FE}=340$ at $I_c=4.99\text{mA}$

$V_{be}=0.758\text{V}$ at $I_b=5.00\text{mA}$

$V_{ceSat}=0.033\text{V}$ at $I_c=5.0\text{mA}$ and $I_b=1.00\text{mA}$

$I_{cLeak}=0.000\text{mA}$

NPN Silicon BJT

Red-B Green-E Blue-C

$h_{FE}=329$ at $I_c=4.99\text{mA}$

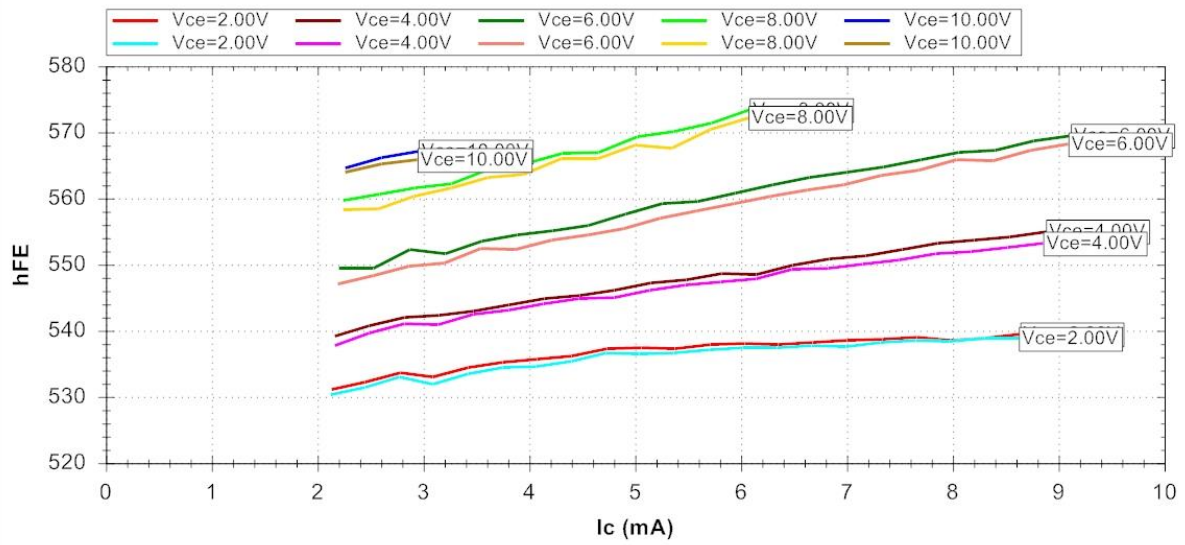
$V_{be}=0.758V$ at $I_b=5.00mA$
 $V_{ceSat}=0.033V$ at $I_c=5.0mA$ and $I_b=1.00mA$
 $I_{cLeak}=0.000mA$

C2291F 79G ("2nd Group Buy" No01)

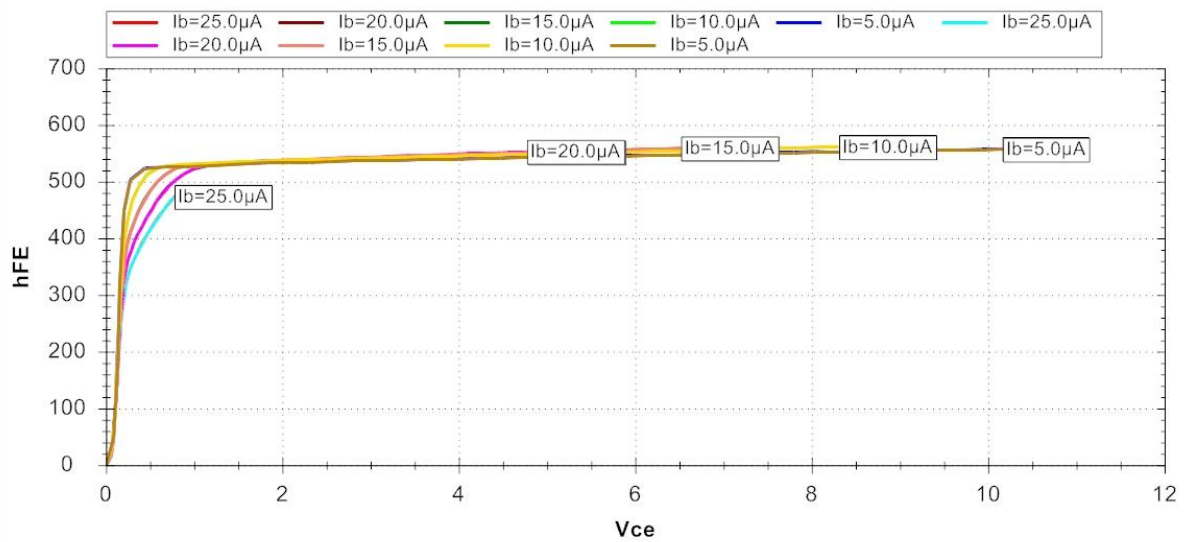
NPN Silicon BJT
Red-B Green-C Blue-E
 $h_{FE}=565$ at $I_c=4.99mA$
 $V_{be}=0.739V$ at $I_b=5.00mA$
 $V_{ceSat}=0.026V$ at $I_c=5.0mA$ and $I_b=1.00mA$
 $I_{cLeak}=0.000mA$

NPN Silicon BJT
Red-B Green-C Blue-E
 $h_{FE}=546$ at $I_c=5.01mA$
 $V_{be}=0.750V$ at $I_b=5.00mA$
 $V_{ceSat}=0.027V$ at $I_c=5.0mA$ and $I_b=1.00mA$
 $I_{cLeak}=0.000mA$

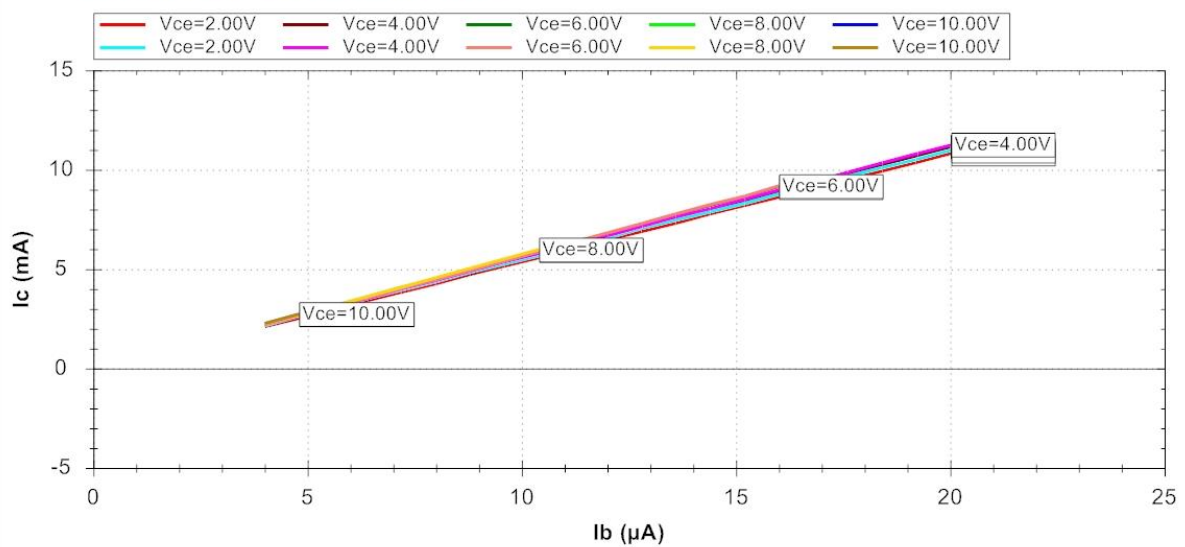
2nd grp buy C2291F 79G (1st) BJT h_{FE} / I_c



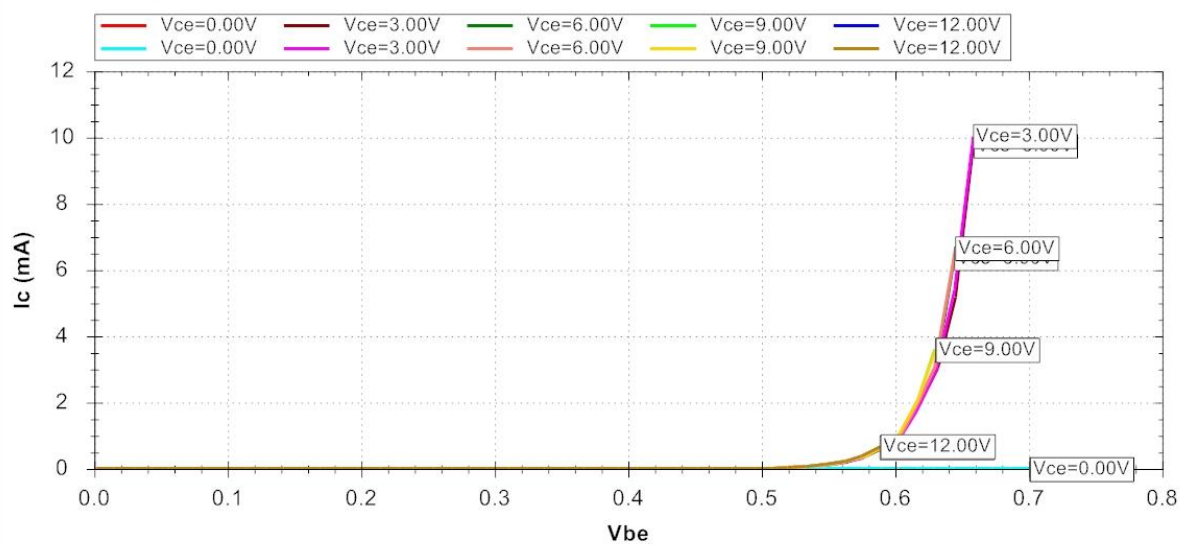
2nd grp buy C2291F 79G (1st) BJT h_{FE} / V_{ce}



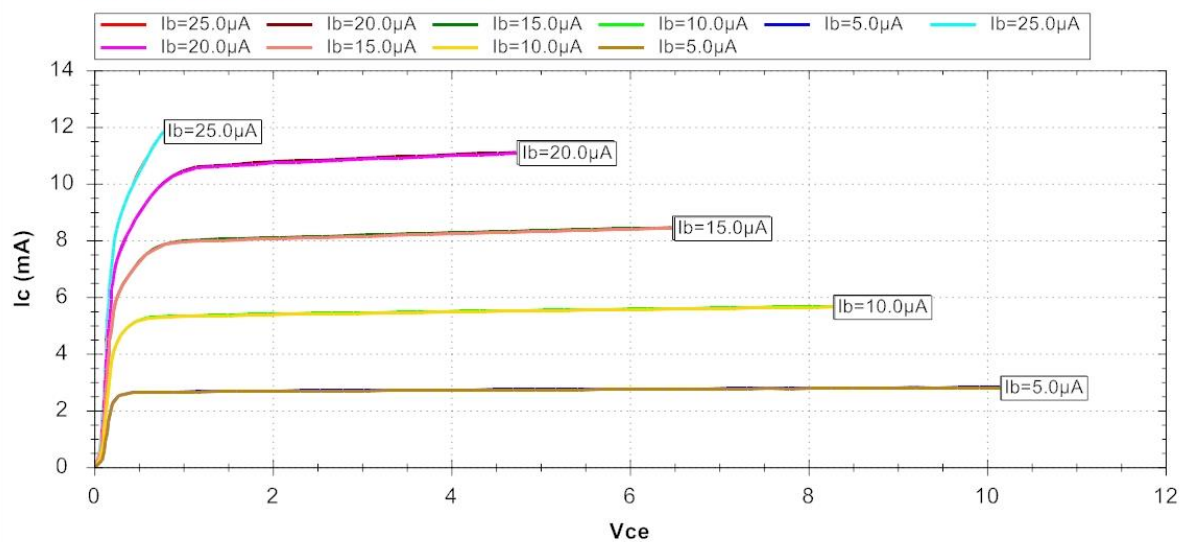
2nd grp buy C2291F 79G (1st) BJT I_c / I_b



2nd grp buy C2291F 79G (1st) BJT I_c / V_{be}



2nd grp buy C2291F 79G (1st) BJT I_c / V_{ce}



A733P 331 ("2nd Group Buy" No01)

PNP Silicon BJT

Red-B Green-C Blue-E

$h_{FE}=382$ at $I_c=5.01\text{mA}$

$V_{be}=0.769\text{V}$ at $I_b=5.00\text{mA}$

$V_{ceSat}=0.026\text{V}$ at $I_c=5.0\text{mA}$ and $I_b=1.00\text{mA}$

$I_{cLeak}=0.000\text{mA}$

D667 A C 1K5 ("2nd Group Buy" No01)

NPN Silicon BJT

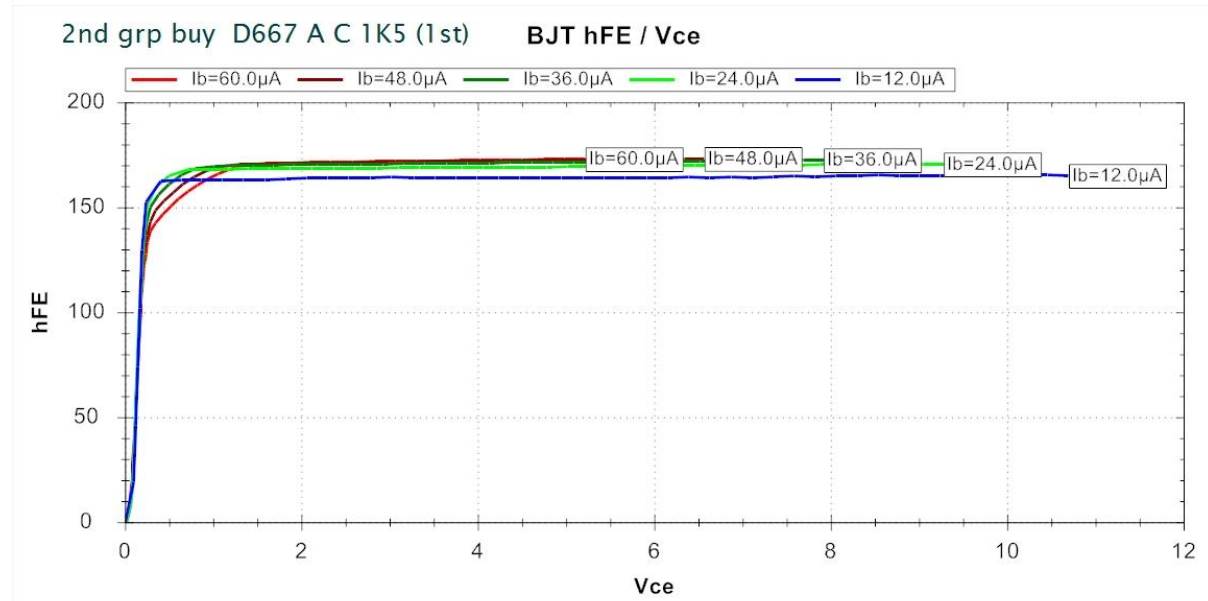
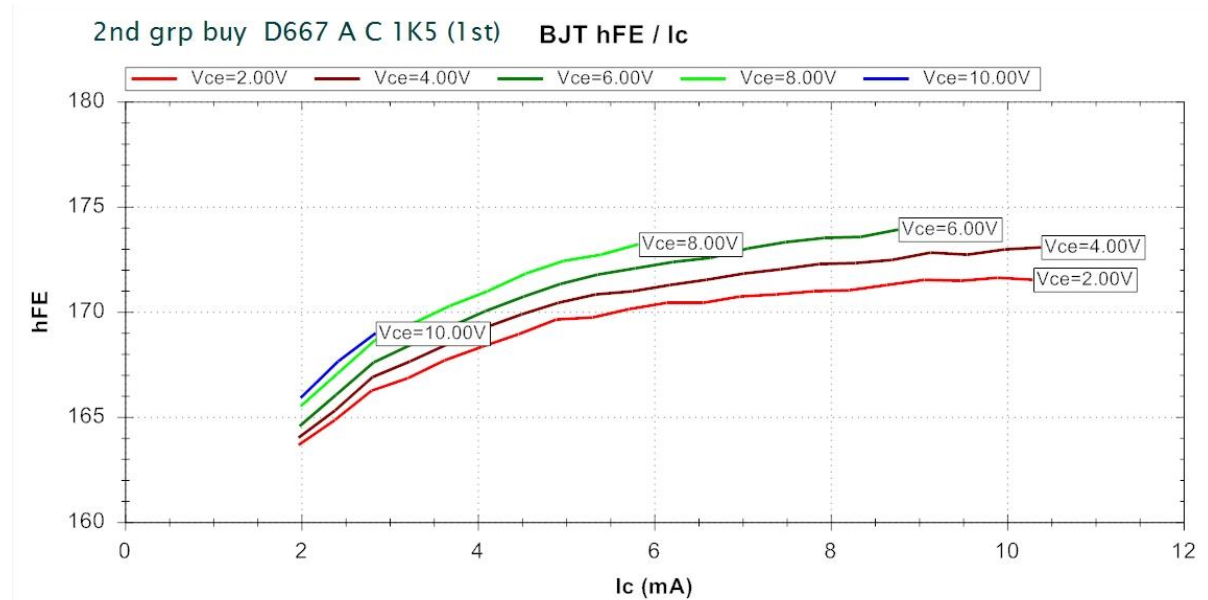
Red-C Green-B Blue-E

$h_{FE}=170$ at $I_C=5.00\text{mA}$

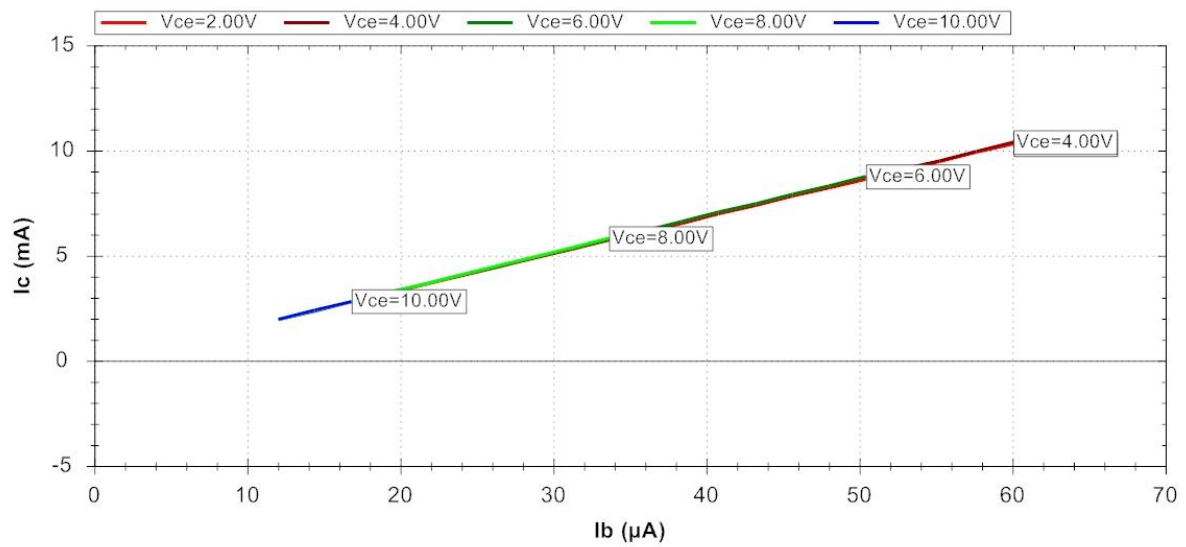
$V_{BE}=0.800\text{V}$ at $I_B=5.00\text{mA}$

$V_{CEsat}=0.026\text{V}$ at $I_C=5.0\text{mA}$ and $I_B=1.00\text{mA}$

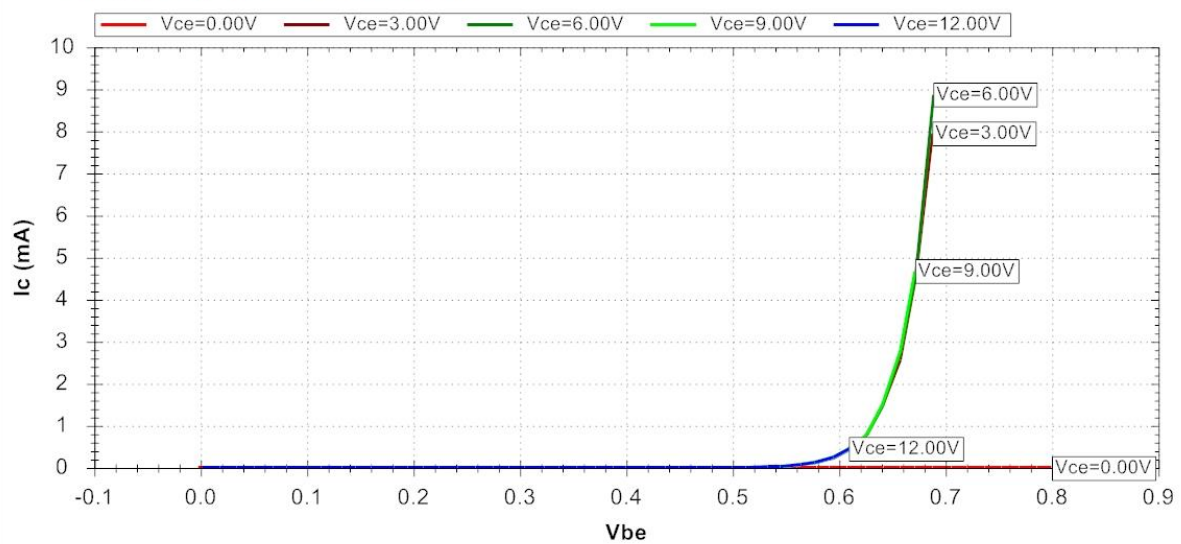
$I_{CLeak}=0.000\text{mA}$



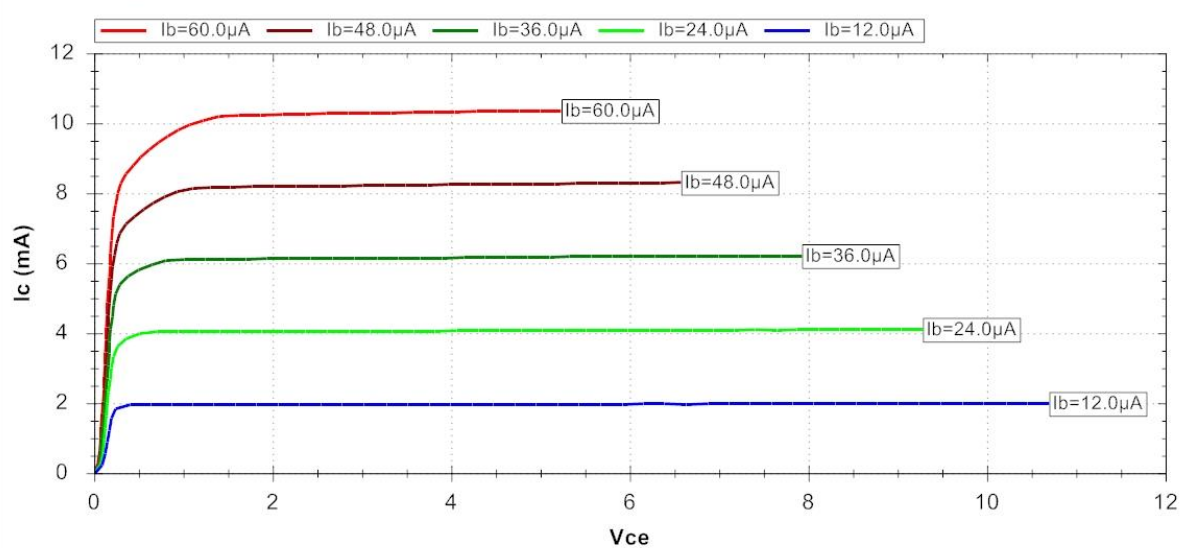
2nd grp buy D667 A C 1K5 (1st) BJT I_c / I_b



2nd grp buy D667 A C 1K5 (1st) BJT I_c / V_{be}



2nd grp buy D667 A C 1K5 (1st) BJT I_c / V_{ce}



B647C BL2 ("2nd Group Buy" No01)

PNP Silicon BJT

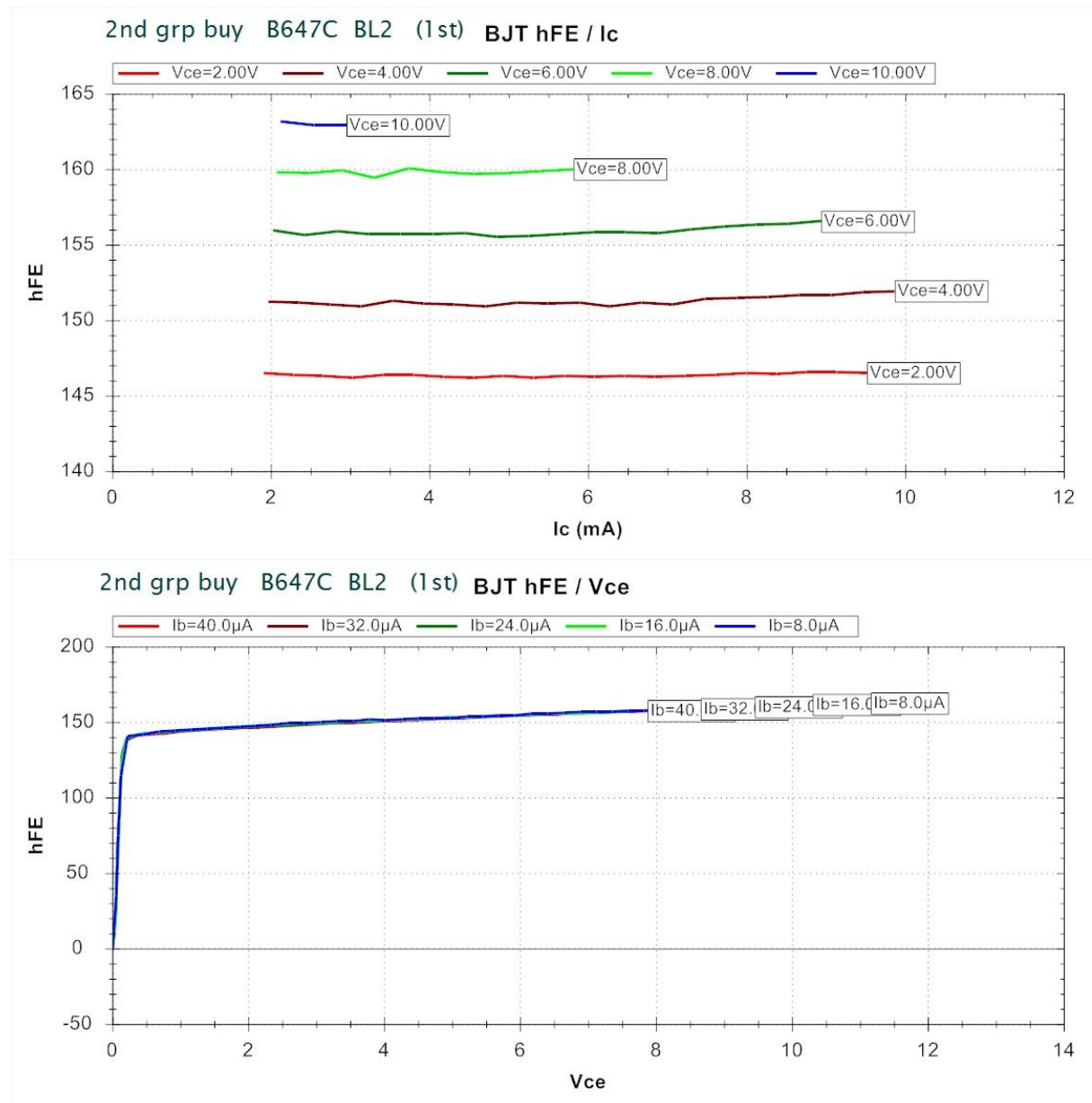
Red-C Green-B Blue-E

$h_{FE}=154$ at $I_C=5.00\text{mA}$

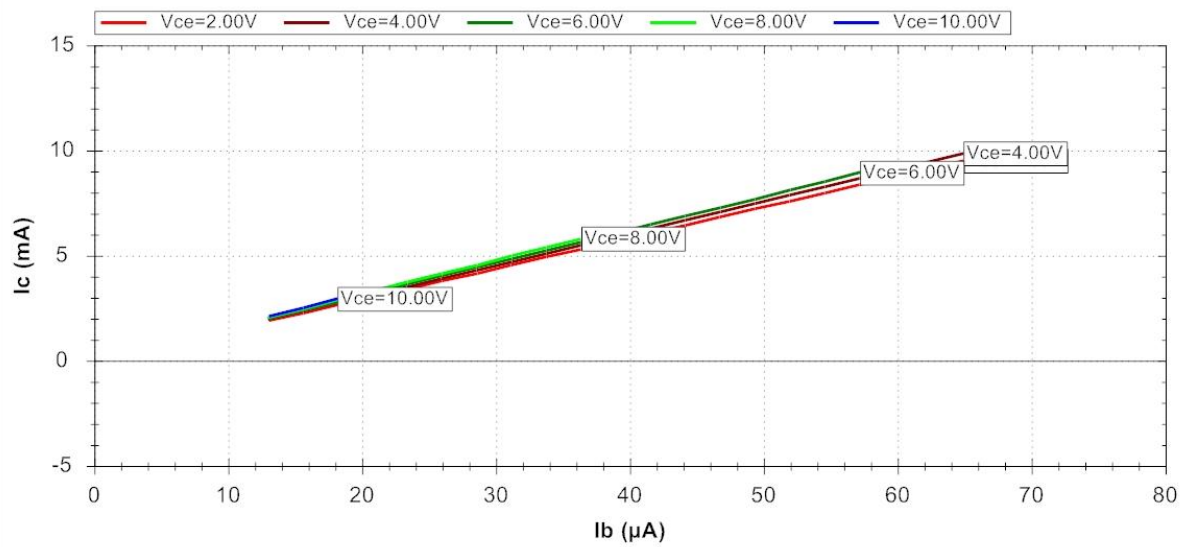
$V_{BE}=0.709\text{V}$ at $I_B=5.00\text{mA}$

$V_{CEsat}=0.018\text{V}$ at $I_C=5.0\text{mA}$ and $I_B=1.00\text{mA}$

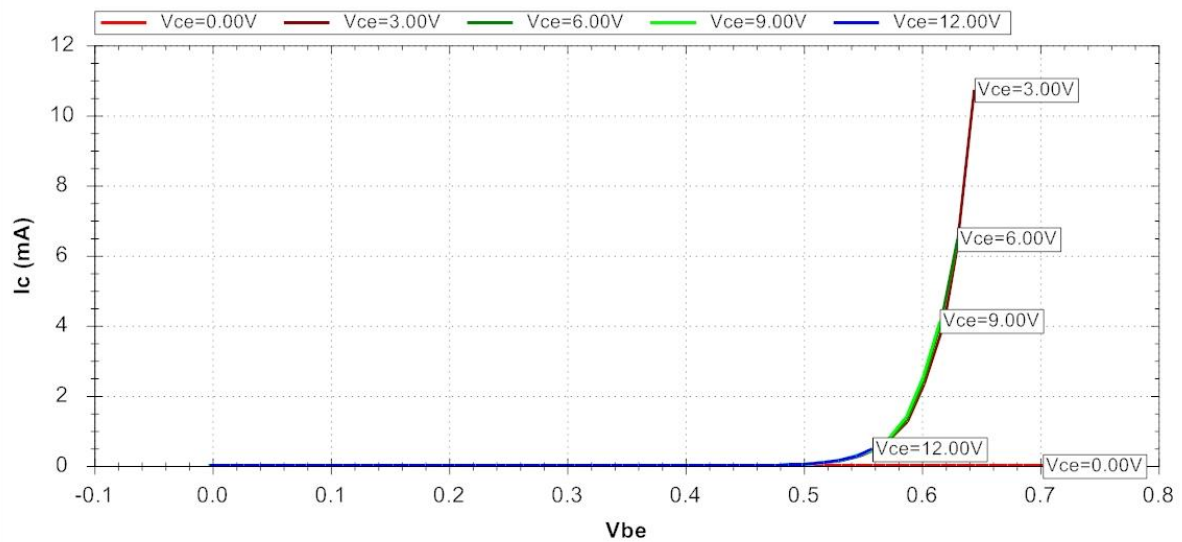
$I_{CLeak}=0.000\text{mA}$



2nd grp buy B647C BL2 (1st) BJT I_c / I_b



2nd grp buy B647C BL2 (1st) BJT I_c / V_{be}



2nd grp buy B647C BL2 (1st) BJT I_c / V_{ce}

